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FORM PTO-1449	SERIAL NO. Not yet assigned	CASE NO. 10808/200
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE Herewith	GROUP ART UNIT Not yet assigned
(use several sheets if necessary)		APPLICANT(S): Hin-Yiu Chung et al.

## REFERENCE DESIGNATION

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
/MDH/	A1	US 2002/0026900 A1	March 7, 2002	Huang et al.		
↓	A2	6,342,691 B1	January 29, 2002	Johnsgard et al.		
	A3	5,872,889	February 16, 1999	Kaltenbrunner et al.		
	A4	5,635,409	June 3, 1997	Meslehi		
	A5	5,581,571	December 3, 1996	Holonyak, Jr. et al.		
	A6	5,385,866	January 31, 1995	Bartush		
	A7	5,313,044	May 17, 1994	Massoud et al.		

## FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	COUNTRY	CLASS/ SUBCLASS	TRANSLATION YES OR NO
/MDH/	A8	GB 2 355 850 A	May 2, 2001	United Kingdom		
↓	A9	WO 99/03141	January 21, 1999	WO		
	A10	GB 2 295 271 A	May 22, 1996	United Kingdom		
	A11	DE 689 19 408 T2	September 29, 1989	Germany		
	A12	DE 37 50 382 T2	March 4, 1987	Germany		

## OTHER ART - NON PATENT LITERATURE DOCUMENTS

EXAMINER INITIAL		(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
/MDH/	A13	Spezialgraphite von SGL Carbon, Produkte für die Halbleitertechnik, SGL Carbon Group, pgs. 2-17, March 2001
↓	A14	H.Q. Jia, H. Chen, W.C. Wang, W.X. Wang, W. Li, Q. Huang and Jiunming Zhou, <i>The Study of Thermal Stability During Wet Oxidation of AlAs</i> , Institute of Physics, Chinese Academy of Sciences, pgs. 484-488, Journal of Crystal Growth, Vol. 223, Issue 4, March 2001.
	A15	William G. Breiland, Michael E. Coltrin, J. Randall Creighton, Hong Q. Hou, Harry K. Moffat and Jeffrey Y. Tsao, <i>Organometallic Vapor Phase Epitaxy</i> , Center for Compound Semiconductor Science and Technology, Sandia National Laboratories, Materials Science and Engineering: R. Reports, Vol. 24, Issue 6, pgs. 241-274, February 1999.
	A16	Copy of International Search Report from International Application Number PCT/DE/02523. 7/26/03
	A17	Copy of Examination Report from International Application Number PCT/DE/02523. 7/26/03

EXAMINER /Monica D. Harrison/	DATE CONSIDERED 06/22/2009
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /MDH.